NSN 5962-01-116-1003

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-116-1003

Body Length:

Between 0.882 inches and 0.925 inches

Body Width:

0.310 inches

Body Height:

0.160 inches

Operating Tempurature Range:

+0.0/+75.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and bipolar and programmable and w/enable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

12 input

Voltage Rating And Type Per Characteristic:

7.0 volts total supply

Time Rating Per Chacteristic:

40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level

output

Memory Device Type:

Prom

Memory Capacity:

Unknown

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0